EAST Search History

EAST Search History (Prior Art)

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L17	1549	257/310.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/08 11:18
L18	287	I17 and (hafnium oxide or "hfo.sub.2")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:18
L19	17	l18 and ("alon" or "AlO.sub.xN.sub.y" or "aln")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:19
L20	4	119 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:19
 L21	862	l17 and (highk or high-k or high dielectric)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:20
L22	734	l21 and (nitrogen or nitri\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:21

L23	714	l22 and silic\$5	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:21
L24	103	l22 and (silic\$5 near3 (highk or high-k or high dielectric))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:22
L25	55	24 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 11:22
L26	1073	257/E21.639.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/08 12:38
L27	287		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:38
L28	17	l19 and ("alon" or "AlO.sub.xN.sub.y" or "aln")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:38
L29	4	l28 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:38

_30	1863	438/240.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/08 12:41
_31	384	l30 and (hafnium oxide or "hfo.sub.2")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:41
_32	51	31 and ("alon" or "AlO.sub.xN.sub.y" or "aln")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:41
_33	27	32 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:42
.34	1594	(26 or 30) and (highk or high-k or high dielectric)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:46
.35	1426	34 and (nitrogen or nitri\$5)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:47
.36	938	35 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:48

L37	142	36 and (silic\$5 near3 (highk or high-k or high dielectric))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/08 12:48
S63	1	(10/550645).APP.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/03/15 14:09
S64	24659	438/142,149,151-154,167,169,172,174,178,197,199,201,211,216,240,257,261,263- 264,287,591,594,682,FOR202.ccls.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/03/21 12:01
S65	36751	257/190-195,201-202,211,213,288,314-316,324-327,368-369,409-413,E51.006,E27.06, E27.108,E29.126,E29.129,E29.13,E29.137,E29.14,E29.158,E29.16,E29.228,E21.457.cds.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/03/21 12:04
S66	33653	(S64 or S65) and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 12:06
S67	2	S66 and (("alon" or "AlO.sub.xN.sub.y" or "aln") same (hafnium oxide or "HfO.sub.2") same (gate near (insulat\$4 or dielectric\$2)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 12:07
S68	83	S66 and (("alon" or "AlO.sub.xN.sub.y" or "aln") and (hafnium oxide or "HfO.sub.2") and (gate near (insulat\$4 or dielectric\$2)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 12:35

S69	5	near (insulat\$4 or dielectric\$2)) same ((anneal\$3 or heat\$4 or thermal\$2) same (silicid \$5))))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 12:49
S70	447		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:08
S71	131	@rlad< "20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:09
S72	85	\$2)) with (silicid\$5) with substrate)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:15
S73	40	@rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:15
S74	1410		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:18
S77	294	with substrate with (gate near (insulat\$4 or dielectric)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:20

578	106		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/03/21 13:21
 679	1178	silicate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:03
3 80	229	silicate	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:04
3 81	77	@rlad< "20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:05
82	1893		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:18
83	1		US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/07 11:20
84	0	diffus\$3 supress\$4	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:24

S85	14	(hafnium oxide or "hfo.sub.2") with ("aln" or aluminum nitride or "alo.sub.xn.sub.y") with diffus\$3	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:24
S86	10	S85 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:24
S87	55	(hafnium oxide or "hfo.sub.2") with (over or between) with ("aln" or aluminum nitride or "alo.sub.xn.sub.y")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:27
S88	19	S87 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:27
S89	2	("6734510").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/07 11:33
S90	110	(("alon" or "AlO.sub.xN.sub.y" or "aln") and ((hafnium oxide or "HfO.sub.2") same (gate near (insulat\$4 or dielectric\$2)) same ((anneal\$3 or heat\$4 or thermal\$2))))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:39
S91	10	S90 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:39

S92	19	barrier with between with two with (highk or high-k or high dielectric)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:48
S93	10	S92 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:48
S94	5	S92 and ("alon" or "AlO.sub.xN.sub.y" or "aln")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:51
S95	0	\$94 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 11:51
S96	2	("20020130340").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/07 11:55
S 97	2	("20020195643").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/07 12:00
S98	217	(tominaga near koji).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/07 12:09

599	49	(iwamoto near kunihiko).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/07 12:09
S100	49	(yasuda near tetsuji).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/07 12:09
S101	99	(nabatame near toshihide).in.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/07 12:10
6102	333	S98 or S99 or S100 or S101	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2011/06/07 12:10
6103	78	S102 and (highk or high-k or high dielectric)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:10
6104	45	S103 and (hafnium oxide or "hfo.sub.2")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:11
6105	14	S104 and ("aln" or aluminum nitride or "alo.sub.xn.sub.y")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:11

S106	78152	(horiba or renesas or rohm).as.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:34
S107	344	S106 and (hafnium oxide or "hfo.sub.2")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:34
S108	339	S106 and ("aln" or aluminum nitride or "alo.sub.xn.sub.y")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:35
S109	20	S107 and S108	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:35
S110		(("alon" or "AlO.sub.xN.sub.y" or "aln") same (hafnium oxide or "HfO.sub.2") same (gate near (insulat\$4 or dielectric\$2))).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 12:41
S111	27	((nitrogen or nitri\$5) same (metal) same (diffus\$3) same (highk or high-k or high dielectric)).clm.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2011/06/07 13:14
S112	2	("6967154").PN.	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2011/06/07 13:17

EAST Search History (Interference)

Ref#	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L39	3303	257/310,324-325,406,411,E21.639.ccls.	USPAT; UPAD	OR	ON	2011/06/08 13:03
L40	3421	438/216,240,261,287,591.cds.	USPAT; UPAD	OR	ON	2011/06/08 13:04
L41	6126	39 or 40	USPAT; UPAD	OR	ON	2011/06/08 13:04
L42	2510	41 and (highk or high-k or high dielectric)	USPAT; UPAD	ADJ	ON	2011/06/08 13:04
L43	537	42 and (silic\$5 near3 (highk or high-k or high dielectric))	USPAT; UPAD	ADJ	ON	2011/06/08 13:04
L44	270	43 and (@pd<"20030324" or @ad<"20030324" or @prad<"20030324" or @rlad<"20030324")	USPAT; UPAD	ADJ	ON	2011/06/08 13:05
L45	254	44 and (nitrid\$5 or nitrogen)	USPAT; UPAD	ADJ	ON	2011/06/08 13:05
L46	25	45 and ("alon" or "AIO.sub.xN.sub.y" or "aln") and (hafnium oxide or "HfO.sub.2")	USPAT; UPAD	ADJ	ON	2011/06/08 13:05
S113	21	(tominaga near koji).in.	USPAT; UPAD	OR	ON	2011/06/07 12:37
S114	8	(iwamoto near kunihiko).in.	USPAT; UPAD	OR	ON	2011/06/07 12:37
S115	8	(yasuda near tetsuji).in.	USPAT; UPAD	OR	ON	2011/06/07 12:38
S116	32	(nabatame near toshihide).in.	USPAT; UPAD	OR	ON	2011/06/07 12:38
S117	52	S113 or S114 or S115 or S116	USPAT; UPAD	OR	ON	2011/06/07 12:38
S118	15	S117 and (hafnium oxide or "HfO.sub.2")	USPAT; UPAD	ADJ	ON	2011/06/07 12:38

6/8/2011 1:38:36 PM

 $\textbf{C:} \ \textbf{Documents and Settings} \ \textbf{mmalek1} \ \textbf{My Documents} \ \textbf{EAST} \ \textbf{Workspaces} \ \textbf{10550645.wsp}$